TOSHIBA BIPOLAR LINEAR INTEGRATED CIRCUIT SILICON MONOLITHIC

TA8029S

FREQUENCY TO VOLTAGE CONVERTER

The TA8029S is a small 9-pin SIP IC incorporating an accurate frequency / voltage converter and two voltage comparators. It has a Schmitt input circuit and becomes active on the positive edge of the input. Its F / V output is stable even when it is supplied with a high-frequency input. Since the VCC pin connects to a shunt regulator, stable frequency detection is assured regardless of the battery voltage. In addition, its wide operating temperature range allows it to be used for a wide variety of applications.

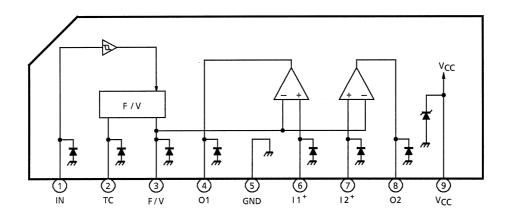
SIP9-P-2.54A

Weight: 0.92 g (typ.)

FEATURES

- Schmitt input circuit incorporated
- Stable F / V output in response to high-frequency input
- Two comparators served by single power supplies are incorporated.
- Shunt regulator incorporated
- Operating temperature range : from −40~85°C
- Small plastic SIP-9 pin

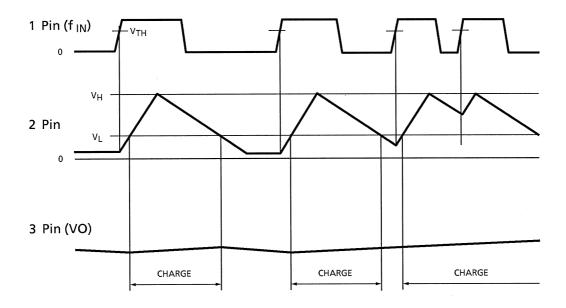
BLOCK DIAGRAM AND PIN LAYOUT



PIN DESCRIPTION

PIN No.	SYMBOL	DESCRIPTION			
1	IN	Frequency input pin. The IC becomes active on the leading edge of the input.			
2	TC	One-shot pulse setting pin which connects to a capacitor.			
3	F/V	F / V conversion output pin which connects to an charging capacitor and resistor. The signal from this pin is also the input to the two built-in comparator.			
4	O1	Comparator 1 output pin. This pin provides an NPN transistor open-collector output and has a current capacity of up to 30mA.			
5	GND	Grounded			
6	l ₁ ⁺	Non-inverted PNP input pin for comparator 1.			
7	l ₂ ⁺	Non-inverted PNP input pin for comparator 2.			
8	O ₂	Comparator 2 output pin. This pin provides an NPN transistor open-collector output and has a current capacity of up to 30mA.			
9	V _{CC}	Power supply pin which connects to a 6V Zener diode.			

TIMING CHART



MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Current	Icc	30	mA
Input Voltage	V _{IN}	-0.3~30	٧
Output Voltage	V _{OUT}	-0.3~30	V
Output Current	lout	30	mA
Power Dissipation	PD	350 (Note)	mW
Operating Temperature	T _{opr}	-40~85	°C
Storage Temperature	T _{stg}	-55~150	°C

Note: Ta≤85°C

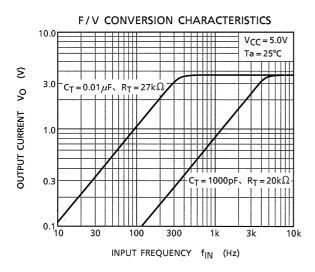
ELECTRICAL CHARACTERISTICS (Ta = 25°C, V_{CC} = 5V)

CHARACTERISTIC	SYMBOL	PIN	TEST CIR- CUIT	TEST CONDITION	MIN	TYP.	MAX	UNIT
Current Consumption	I _{CC}	V _{CC}	_		_	3.0	5	mA
Regulated Voltage	V _R	V _{CC}	_	I _{CC} = 12mA	5.5	6.0	6.5	V
Input Current	I _{IN}	IN	_	V _{IN} = 0~20V	-10	_	10	μΑ
Input Voltage	V _{IH}	IN	_		2.8	_	_	- V
	V _{IL}		_		_	_	0.8	
Input Rise Rate	V _{LH}	IN	_		0.5	_	_	V / ms
Input Fall Rate	V _{HL}	IN	_		0.1	_	_	V / ms
	l _{OL}	тс	_	V _{TC} = 2.5V	_	43	_	μА
Output Current	I _{OH}		_	V _{TC} = 2.5V	_	-73	_	
	I _{OH}	F/V	_		-250	-350	-500	
F / V Conversion Coefficient	К	F/V	_	$C_T = 0.01 \mu F, R_T = 27 k\Omega$ f = 100Hz (Note 1)	_	7.8	_	_
Linearity			_	$C_T = 0.01 \mu F, R_T = 27 k\Omega$ (Note 2)	_	±3.0	_	%
Input Offset Voltage	V _{IO}	l ₁ ⁺ / l ₂ ⁺	_		_	2	10	mV
Input Current	I _{IN}	l ₁ ⁺ / l ₂ ⁺	_		_	-0.2	-1	μΑ
Common-mode Input Voltage	V _{CM}	l ₁ ⁺ / l ₂ ⁺	_		0	_	V _{CC} -1.5	V
Voltage Gain	A _V		_		_	100	_	dB
Output Voltage	V _{OL}	O ₁ / O ₂	_	I _{OL} = 10mA	_	_	0.5	V
Output Leakage Current	I _{LEAK}	O ₁ / O ₂	_	V _O = 16V	_	_	5	μΑ

Notes:

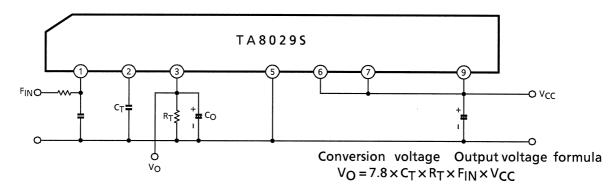
- 1. Calculated from $V_O = K \cdot V_{CC} \cdot C_T \cdot R_T \cdot f$
- 2. Straight line deviation at f = 50Hz and f = 150Hz relative to that at f = 100Hz

STANDARD CHARACTERISTICS

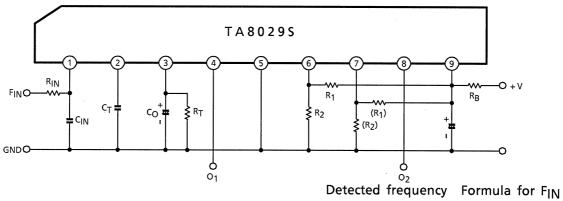


EXAMPLE OF APPLICATION CIRCUIT

1. FREQUENCY-VOLTAGE CONVERSION CIRCUIT



2. FREQUENCY DETECTION CIRCUIT



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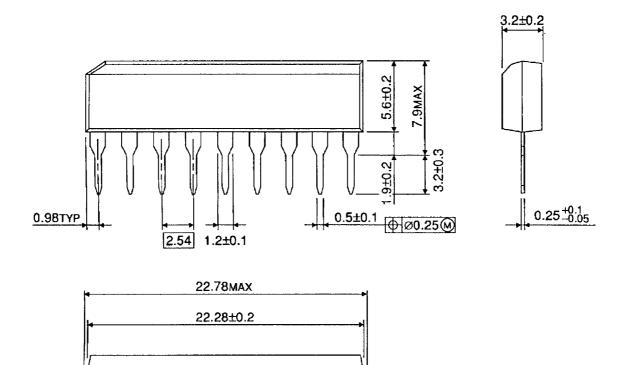
FIN = $\frac{R_2}{7.8 \times C_T \times R_T \times (R_1 + R_2)}$

RECOMMENDED CONDITION

PART NAME	MIN	MAX	UNIT
C _T	1000		pF
R _T	20		kΩ
f _{IN}		5	kHz

PACKAGE DIMENSIONS

SIP9-P-2.54A Unit: mm



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Weight: 0.92g (Typ.)

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RESTRICTIONS ON PRODUCT USE

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